

# 8098/8398/8798 COMMERCIAL/EXPRESS HMOS MICROCONTROLLER

- 8798: an 8098 with 8 Kbytes of On-Chip EPROM
- 8398: an 8098 with 8 Kbytes of On-Chip ROM

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|---|--|
| <ul style="list-style-type: none"> <li>■ 232 Byte Register File</li> <li>■ Register-to-Register Architecture</li> <li>■ 10-Bit A/D Converter with S/H</li> <li>■ Two 8-Bit and Two 4-Bit I/O Ports</li> <li>■ 20 Interrupt Sources</li> <li>■ Pulse-Width Modulated Output</li> <li>■ ROM/EPROM Lock</li> <li>■ High Speed I/O Subsystem</li> <li>■ Extended Temperature Available</li> </ul> | <ul style="list-style-type: none"> <li>■ Full Duplex Serial Port</li> <li>■ Dedicated Baud Rate Generator</li> <li>■ 6.25 <math>\mu</math>s 16 x 16 Multiply</li> <li>■ 6.25 <math>\mu</math>s 32/16 Divide</li> <li>■ 16-Bit Watchdog Timer</li> <li>■ Four 16-Bit Software Timers</li> <li>■ Two 16-Bit Counter/Timers</li> <li>■ Run-Time Programmable EPROM</li> <li>■ Extended Burn-In Available</li> </ul> |
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The MCS<sup>®</sup>-96 family of 16-bit microcontrollers consists of many members, all of which are designed for high-speed control functions. The 8X98 members were designed specifically for those applications that require the speed of a 16-bit microcontroller but are limited by board space and cost requirements to an 8-bit external bus. The 8X98 members are produced using Intel's HMOS-III process.

The CPU supports bit, byte, and word operations. Thirty-two bit double-words are supported for a subset of the instruction set. With a 12 MHz input frequency the 8098 can do a 16-bit addition in 1.0  $\mu$ s and a 16 x 16-bit multiply or 32/16 divide in 6.25  $\mu$ s. Instruction execution times average 1 to 2  $\mu$ s in typical applications.

Four high-speed trigger inputs are provided to record the times at which external events occur. Six high-speed pulse generator outputs are provided to trigger external events at preset times. The high-speed output unit can simultaneously perform software timer functions. Up to four 16-bit software timers can be in operation at once.

The on-chip A/D converter includes a Sample and Hold, and converts up to 4 multiplexed analog input channels to 10-bit digital values. With a 12 MHz crystal, each conversion takes 22  $\mu$ s.

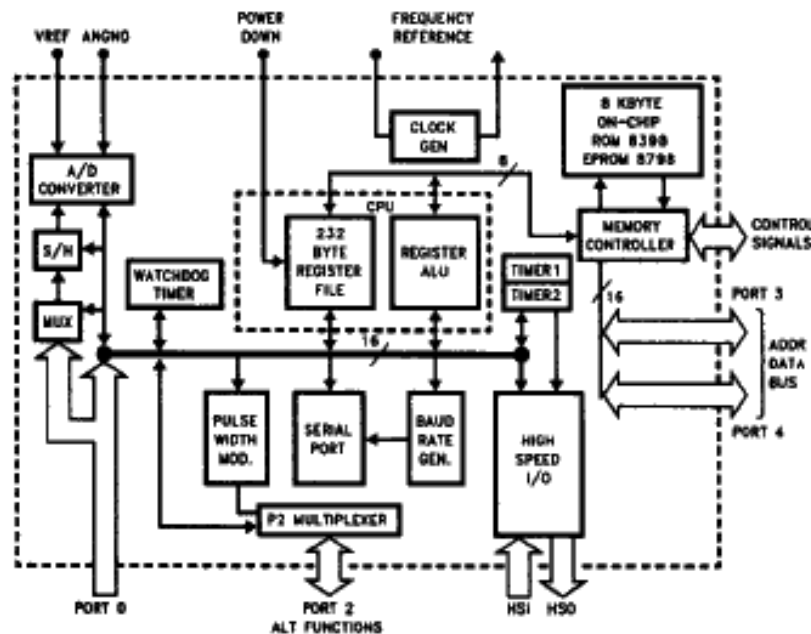


Figure 1. 8X98 Block Diagram

270532-1



8098/8398/8798



### PACKAGING

The 8098 is available in a 48-pin package with and without on-chip ROM or EPROM. The MCS-96 numbering system for the 8X98 devices is shown in Figure 4. Figure 6 shows the pinout for the 48-pin package. The 48-pin version is offered in a Dual-In-Line package.

Factory Masked ROM	CPU	User Programmable	
		EPROM	OTP
48-Pin	48-Pin	48-Pin	48-Pin
8398	8098	8798	8798

Figure 3. MCS®-96 Packaging—8098

**Package Designators:**  
C = Ceramic DIP  
P = Plastic DIP

**Prefix Designators:**  
T = Extended Temperature  
L = Extended Temperature with 160 Hours Burn-In

Package Type	$\theta_{ja}$	$\theta_{jc}$
48L Plastic DIP	38°C/W	19°C/W
48L Ceramic DIP	26°C/W	6.5°C/W

Figure 4. 8X98 Thermal Characteristics

All thermal impedance data is approximate for static air conditions at 1W of power dissipation. Values will change depending on operating conditions and application. See the Intel *Packaging Handbook* (Order Number 240800) for a description of Intel's thermal impedance test methodology.

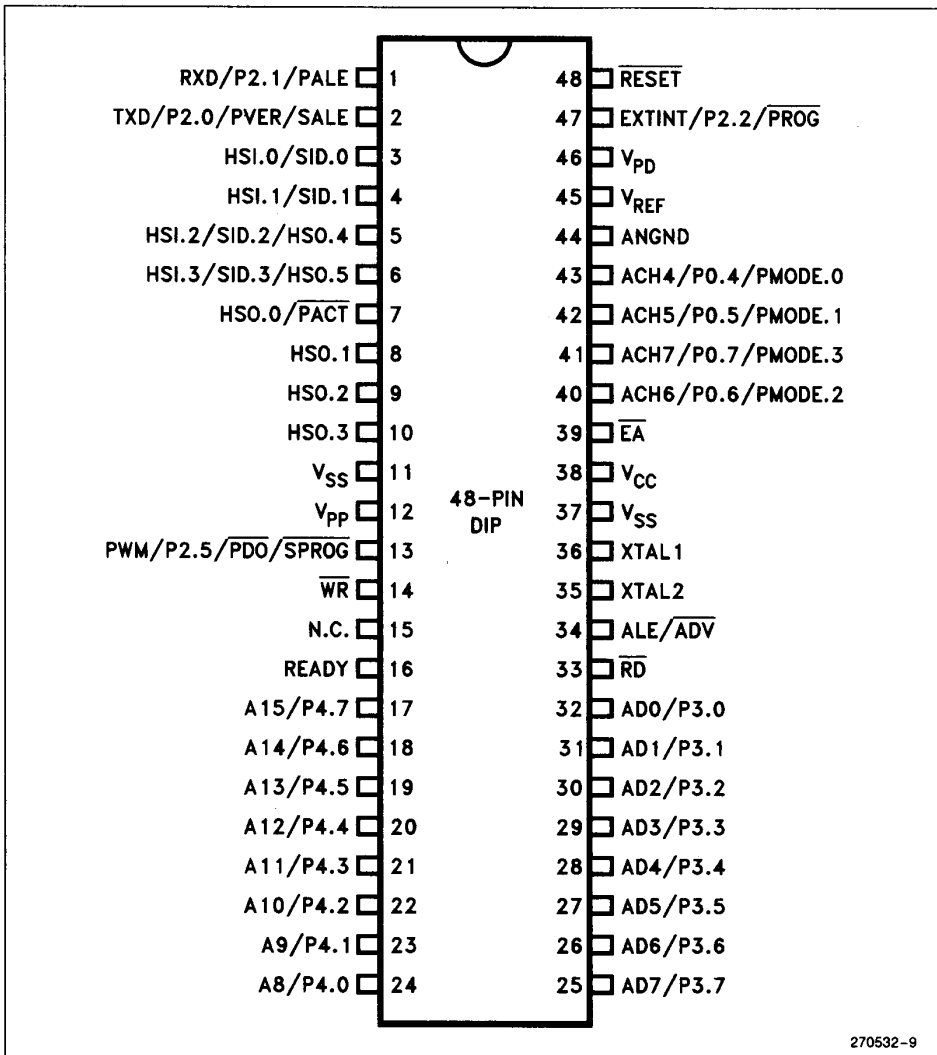


Figure 5. 48-Pin Package

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## PIN DESCRIPTIONS

Symbol	Name and Function
V <sub>CC</sub>	Main supply voltage (5V).
V <sub>SS</sub>	Digital circuit ground (0V). There are two V <sub>SS</sub> pins, both of which must be connected.
V <sub>PD</sub>	RAM standby supply voltage (5V). This voltage must be present during normal operation. In a Power Down condition (i.e. V <sub>CC</sub> drops to zero), if $\overline{\text{RESET}}$ is activated before V <sub>CC</sub> drops below spec and V <sub>PD</sub> continues to be held within spec., the top 16 bytes in the Register File will retain their contents.
V <sub>REF</sub>	Reference voltage for the A/D converter (5V). V <sub>REF</sub> is also the supply voltage to the analog portion of the A/D converter and the logic used to read Port 0. Must be connected for A/D and Port 0 to function.
ANGND	Reference ground for the A/D converter. Must be held at nominally the same potential as V <sub>SS</sub> .
V <sub>PP</sub>	Programming voltage for the EPROM devices. It should be 12.75V when programming and will float to 5V otherwise. The pin should not be above V <sub>CC</sub> for ROM or CPU devices. This pin must float in the application circuit on EPROM devices.
XTAL1	Input of the oscillator inverter and of the internal clock generator.
XTAL2	Output of the oscillator inverter.
RESET	Reset input to the chip. Input low for a minimum 10XTAL1 cycles to reset the chip. The subsequent low-to-high transition re-synchronizes CLKOUT and commences a 10-state-time RESET sequence.
$\overline{\text{EA}}$	Input for memory select (External Access). $\overline{\text{EA}}$ equal to a TTL-high causes memory accesses to locations 2000H through 3FFFH to be directed to on-chip ROM. $\overline{\text{EA}}$ equal to a TTL-low causes accesses to these locations to be directed to off-chip memory. $\overline{\text{EA}}$ equal to +12.75V causes the device to enter the Programming Mode.
ALE/ $\overline{\text{ADV}}$	Address Latch Enable or Address Valid output, as selected by CCR. Both pin options provide a latch to demultiplex the address from the address/data bus. When the pin is $\overline{\text{ADV}}$ , it goes inactive high at the end of the bus cycle. ALE/ $\overline{\text{ADV}}$ is activated only during external memory accesses.
$\overline{\text{RD}}$	Read signal output to external memory. $\overline{\text{RD}}$ is activated only during external memory reads.
$\overline{\text{WR}}$	Write output to external memory. $\overline{\text{WR}}$ is activated only during external memory writes.
READY	Ready input to lengthen external memory cycles. If the pin is low prior to the falling edge of CLKOUT, the memory controller goes into a wait mode until the next positive transition of CLKOUT occurs with READY high. When the external memory is not being used, READY has no effect. Internal control of the number of wait states inserted into a bus cycle held not ready is available in the CCR.

**PIN DESCRIPTIONS** (Continued)

Symbol	Name and Function
HSI	Inputs to High Speed Input Unit. Four HSI pins are available: HSI.0, HSI.1, HSI.2 and HSI.3. Two of them (HSI.2 and HSI.3) are shared with the HSO Unit.
HSO	Outputs from High Speed Output Unit. Six HSO pins are available: HSO.0, HSO.1, HSO.2, HSO.3, HSO.4 and HSO.5. Two of them (HSO.4 and HSO.5) are shared with the HSI Unit.
Port 0	4-bit high impedance input-only port. These pins can be used as digital inputs and/or as analog inputs to the on-chip A/D converter.
Port 2	4-bit multi-functional port. Its pins are shared with other functions in the 8098.
Ports 3 and 4	8-bit bidirectional I/O ports with open drain outputs. These pins are shared with the multiplexed address/data bus which has strong internal pullups. Ports 3 and 4 are also used as a command, address and data path by EPROM devices in the Programming Mode.
PMODE	Determines the EPROM programming mode.
PACT	A low signal in Auto Programming Mode indicates that programming is in progress. A high signal indicates programming is complete.
PVAL	A low signal in Auto Programming Mode indicates that the device programmed correctly.
SALE	A falling edge in Auto Programming Mode indicates that Ports 3 and 4 contain valid programming address/command information (output from master).
SPROG	A falling edge in Auto Programming Mode indicates that Ports 3 and 4 contain valid programming data (output from master).
SID	Assigns a pin of Ports 3 and 4 to each slave to pass programming verification.
PALE	A falling edge in Slave Programming Mode and Auto Configuration Byte Programming Mode indicates that Ports 3 and 4 contain valid programming address/command information (input to slave).
PROG	A falling edge in Slave Programming Mode indicates that Ports 3 and 4 contain valid programming data (input to slave).
PVER	A high signal in Slave Programming Mode and Auto Configuration Byte Programming Mode indicates the byte programmed correctly.
PVAL	A high signal in Slave Programming Mode indicates the device programmed correctly.
PDO	A low signal in Slave Programming Mode indicates that the PROG pulse was applied for longer than allowed.

**ELECTRICAL CHARACTERISTICS  
ABSOLUTE MAXIMUM RATINGS\***

Ambient Temperature Under Bias	-55°C to +125°C
Storage Temperature	-60°C to +150°C
Voltage from $\overline{EA}$ or $V_{PP}$ to $V_{SS}$ or ANGND	-0.3V to +13.0V
Voltage from Any Other Pin to $V_{SS}$ or ANGND	-0.3V to +7.0V(1)
Average Output Current from Any Pin	10 mA
Power Dissipation(2)	1.5W

**NOTES:**

1. This includes  $V_{PP}$  on ROM and CPU only devices.
2. Power dissipation is based on package heat transfer limitations, not device power consumption.

NOTICE: This data sheet contains preliminary information on new products in production. It is valid for the devices indicated in the revision history. The specifications are subject to change without notice.

\*WARNING: Stressing the device beyond the "Absolute Maximum Ratings" may cause permanent damage. These are stress ratings only. Operation beyond the "Operating Conditions" is not recommended and extended exposure beyond the "Operating Conditions" may affect device reliability.

**OPERATING CONDITIONS**

(All characteristics specified in this data sheet apply to these operating conditions unless otherwise noted.)

Symbol	Parameter	Min	Max	Units
$T_A$	Ambient Temperature Under Bias <b>Commercial</b> Temp.	0	+70	C
$T_A$	Ambient Temperature Under Bias <b>Extended</b> Temp.	-40	+85	C
$V_{CC}$	Digital Supply Voltage	4.50	5.50	V
$V_{REF}$	Analog Supply Voltage	4.50	5.50	V
$F_{OSC}$	Oscillator Frequency	6.0	12	MHz
$V_{PD}$	Power-Down Supply Voltage	4.50	5.50	V

**NOTE:**

ANGND and  $V_{SS}$  should be nominally at the same potential.

**DC CHARACTERISTICS**

Symbol	Parameter	Min	Max	Units	Test Conditions
$I_{CC}$	$V_{CC}$ Supply Current <b>Commercial</b> Temp.		240	mA	All Outputs Disconnected.
$I_{CC}$	$V_{CC}$ Supply Current <b>Extended</b> Temp.		270	mA	
$I_{CC}$	$V_{CC}$ Supply Current ( $T_A \geq 70^\circ\text{C}$ )		185	mA	
$I_{PD}$	$V_{PD}$ Supply Current		1	mA	Normal operation and Power-Down.
$I_{REF}$	$V_{REF}$ Supply Current <b>Commercial</b> Temp.		8	mA	
$I_{REF}$	$V_{REF}$ Supply Current <b>Extended</b> Temp.		10	mA	
$V_{IL}$	Input Low Voltage	-0.3	+0.8	V	

**DC CHARACTERISTICS** (Continued)

Symbol	Parameter	Min	Max	Units	Test Conditions
V <sub>IH</sub>	Input High Voltage (Except $\overline{\text{RESET}}$ , NMI, XTAL1)	2.0	V <sub>CC</sub> + 0.5	V	
V <sub>IH1</sub>	Input High Voltage, $\overline{\text{RESET}}$ Rising	2.4	V <sub>CC</sub> + 0.5	V	
V <sub>IH2</sub>	Input High Voltage, $\overline{\text{RESET}}$ Falling Hysteresis	2.1	V <sub>CC</sub> + 0.5	V	
V <sub>IH3</sub>	Input High Voltage, NMI, XTAL1	2.2	V <sub>CC</sub> + 0.5	V	
I <sub>LI</sub>	Input Leakage Current to each pin of HSI, P3, P4, and to P2.1.		± 10	μA	V <sub>in</sub> = 0 to V <sub>CC</sub>
I <sub>LI1</sub>	DC Input Leakage Current to each pin of P0		+ 3	μA	V <sub>in</sub> = 0 to V <sub>CC</sub>
I <sub>IH</sub>	Input High Current to $\overline{\text{EA}}$		100	μA	V <sub>IH</sub> = 2.4V
I <sub>IL</sub>	Input Low Current to each pin of P1 and to P2.6, P2.7 <b>Commercial</b> Temp.		- 125	μA	V <sub>IL</sub> = 0.45V
I <sub>IL</sub>	Input Low Current to each pin of P1 and to P2.6, P2.7 <b>Extended</b> Temp.		- 150	μA	
I <sub>IL1</sub>	Input Low Current to $\overline{\text{RESET}}$	- 0.25	- 2	mA	V <sub>IL</sub> = 0.45V
I <sub>IL2</sub>	Input Low Current P2.2		- 50	μA	V <sub>IL</sub> = 0.45V
V <sub>OL</sub>	Output Low Voltage on P3, P4 when used as ports		0.45	V	I <sub>OL</sub> = 0.8 mA (Note 1)
V <sub>OL1</sub>	Output Low Voltage on P3, P4 when used as ports		0.75	V	I <sub>OL</sub> = 2.0 mA (Notes 1, 2, 3)
V <sub>OL2</sub>	Output Low Voltage on Standard Output pins, $\overline{\text{RESET}}$ and Bus/Control Pins		0.45	V	I <sub>OL</sub> = 2.0 mA (Notes 1, 2, 3)
V <sub>OH1</sub>	Output High Voltage on Standard Output pins and Bus/Control pins	2.4		V	I <sub>OH</sub> = - 200 μA (Note 1)
I <sub>OH3</sub>	Output High Current on $\overline{\text{RESET}}$	- 50		μA	V <sub>OH</sub> = 2.4V
C <sub>S</sub>	Pin Capacitance (Any Pin to V <sub>SS</sub> )		10	pF	F <sub>TEST</sub> = 1.0 MHz

**NOTES:**

- Standard Output Pins include TXD, RXD (Mode 0 only), PWM, and HSO pins. Bus/Control pins include ALE,  $\overline{\text{RD}}$ ,  $\overline{\text{WR}}$ , AD0-AD7 and A8-A15.
- Maximum current per pin must be externally limited to the following values if V<sub>OL</sub> is held above 0.45V.  
 I<sub>OL</sub> on Ports 3 and 4 when used as ports: 4.0 mA  
 I<sub>OL</sub> on standard output pins and  $\overline{\text{RESET}}$ : 8.0 mA  
 I<sub>OL</sub> on Bus/Control pins: 2.0 mA
- During normal (non-transient) operation the following limits apply:  
 Total I<sub>OL</sub> on P2.0,  $\overline{\text{RESET}}$  and all HSO pins must not exceed 15 mA.  
 Total I<sub>OL</sub> on Port 3 must not exceed 10 mA.  
 Total I<sub>OL</sub> on P2.5 and Port 4 must not exceed 20 mA.

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**AC CHARACTERISTICS** Test Conditions: Load Capacitance on Output Pins = 80 pF

**TIMING REQUIREMENTS** (The system must meet these specifications to work with the 8X98.)

Symbol	Parameter	Min	Max	Units
T <sub>LLYV</sub>	End of ALE/ $\overline{ADV}$ to READY Valid		2 T <sub>OSC</sub> - 70	ns
T <sub>LLYH</sub>	End of ALE/ $\overline{ADV}$ to READY High	2 T <sub>OSC</sub> + 40	4 T <sub>OSC</sub> - 80	ns
T <sub>LYH</sub>	Non-Ready Time		1000	ns
T <sub>AVDV</sub> <sup>(1)</sup>	Address Valid to Input Data Valid		5 T <sub>OSC</sub> - 120 <sup>(2)</sup>	ns
T <sub>RLDV</sub>	$\overline{RD}$ Active to Input Data Valid		3 T <sub>OSC</sub> - 100 <sup>(2)</sup>	ns
T <sub>RHDX</sub>	Data Hold after $\overline{RD}$ Inactive	0		ns
T <sub>RHDZ</sub>	$\overline{RD}$ Inactive to Input Data Float	0	T <sub>OSC</sub> - 25	ns

**NOTE:**

1. The term "Address Valid" applies to A0-A15.
2. If wait states are used, add 3 T<sub>OSC</sub> \* N where N = number of states.

**TIMING RESPONSES** (8X98 devices meet these specs.)

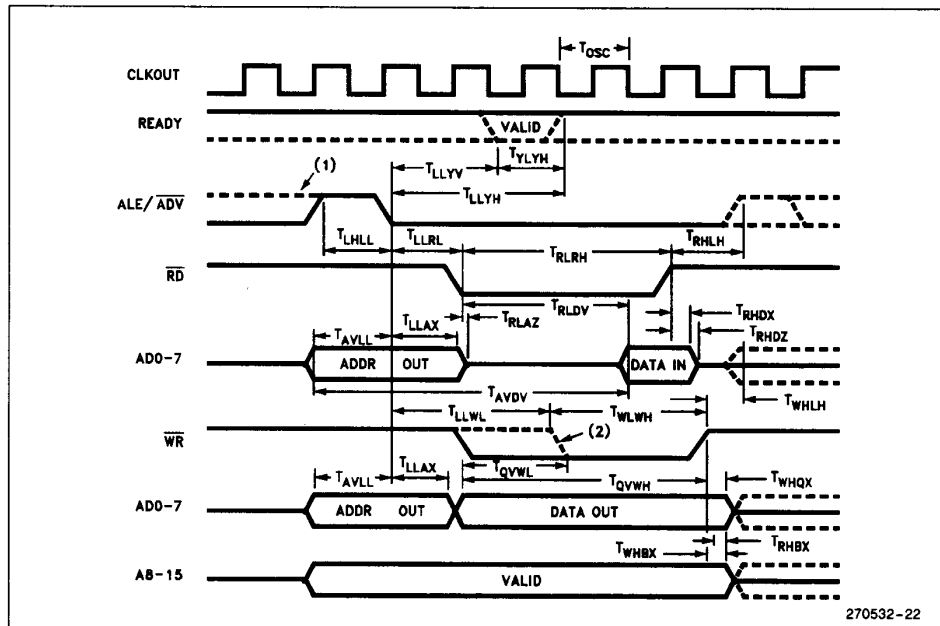
Symbol	Parameter	Min	Max	Units
F <sub>XTAL</sub>	Oscillator Frequency	6.0	12.0	MHz
T <sub>OSC</sub>	Oscillator Period	83	166	ns
T <sub>LHLL</sub>	ALE/ $\overline{ADV}$ High Time	T <sub>OSC</sub> - 30	T <sub>OSC</sub> + 35 <sup>(3)</sup>	ns
T <sub>AVLL</sub> <sup>(4)</sup>	Address Setup to End of ALE/ $\overline{ADV}$	T <sub>OSC</sub> - 50		ns
T <sub>RLAZ</sub> <sup>(5)</sup>	$\overline{RD}$ or $\overline{WR}$ Low to Address Float <b>Commercial</b> Temp.	Typ. = 0	10	ns
T <sub>RLAZ</sub> <sup>(5)</sup>	$\overline{RD}$ or $\overline{WR}$ Low to Address Float <b>Extended</b> Temp.		25	ns
T <sub>LLRL</sub>	End of ALE/ $\overline{ADV}$ to $\overline{RD}$ Active	T <sub>OSC</sub> - 40		ns
T <sub>LLAX</sub> <sup>(5)</sup>	Address Hold after End of ALE/ $\overline{ADV}$	T <sub>OSC</sub> - 40		ns
T <sub>WLWH</sub> <sup>(6)</sup>	$\overline{WR}$ Pulse Width	3 T <sub>OSC</sub> - 35 <sup>(2)</sup>		ns
T <sub>WLWH</sub> <sup>(7)</sup>	$\overline{WR}$ Pulse Width	2 T <sub>OSC</sub> - 35 <sup>(2)</sup>	2 T <sub>OSC</sub> + 40	ns
T <sub>QVWH</sub>	Output Data Valid to End of $\overline{WR}$	3 T <sub>OSC</sub> - 60 <sup>(2)</sup>		ns
T <sub>WHQX</sub>	Output Data Hold after $\overline{WR}$	T <sub>OSC</sub> - 50		ns
T <sub>WHLH</sub>	End of $\overline{WR}$ to ALE/ $\overline{ADV}$ High	T <sub>OSC</sub> - 75		ns
T <sub>RLRH</sub>	$\overline{RD}$ Pulse Width	3 T <sub>OSC</sub> - 30 <sup>(2)</sup>		ns

**TIMING RESPONSES** (8X98 devices meet these specs.) (Continued)

Symbol	Parameter	Min	Max	Units
$T_{RHLH}$	End of $\overline{RD}$ to ALE/ $\overline{ADV}$ High	$T_{OSC} - 45$		ns
$T_{RHBX}$	$\overline{RD}$ High to A8-A15 Inactive	$T_{OSC} - 25$	$T_{OSC} + 30$	ns
$T_{WHBX}$	$\overline{WR}$ High to A8-A15 Inactive	$T_{OSC} - 50$	$T_{OSC} + 100$	ns
$T_{LLWL}^{(6)}$	ALE/ $\overline{ADV}$ Low to $\overline{WR}$ Low	$T_{OSC} - 40$		ns
$T_{LLWL}^{(7)}$	ALE/ $\overline{ADV}$ Low to $\overline{WR}$ Low	$2 T_{OSC} - 30$	$2 T_{OSC} + 55$	ns
$T_{QVWL}^{(6)}$	Output Data Valid to $\overline{WR}$ Low	$T_{OSC} - 60$		ns
$T_{QVWL}^{(7)}$	Output Data Valid to $\overline{WR}$ Low	$T_{OSC} - 30$		ns

**NOTES:**

2. If more than one wait state is desired, add 3  $T_{osc}$  for each additional wait state.
3. Max spec applies only to ALE. Min spec applies to both ALE and  $\overline{ADV}$ .
4. The term "Address Valid" applies to A00-A07, A8-A15.
5. The term "Address" in this definition applies to A00-A07.
6. Write Strobe Mode is not selected.
7. Write Strobe Mode is selected.

**WAVEFORM—SYSTEM BUS TIMINGS**


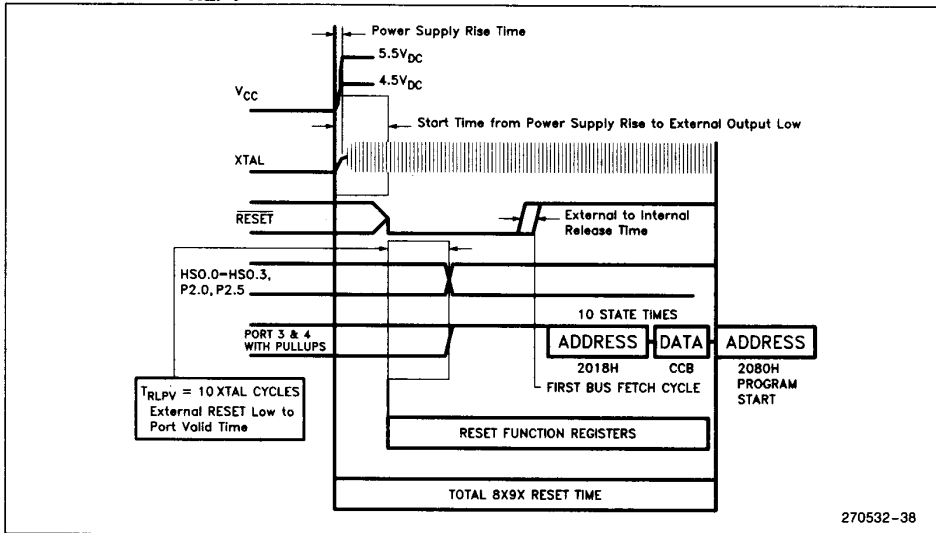
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**NOTES:**

1. When  $\overline{ADV}$  selected.
2. When Write Strobe Mode selected.



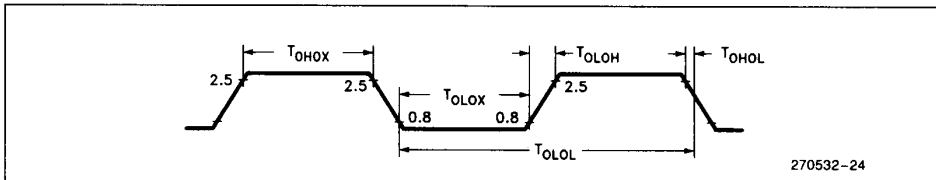
**WAVEFORM— $T_{RLPV}$**



**EXTERNAL CLOCK DRIVE**

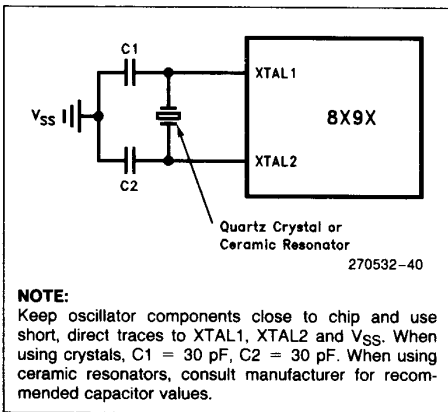
Symbol	Parameter	Min	Max	Units
$1/T_{OLOL}$	Oscillator Frequency	6	12	MHz
$T_{OHOX}$	High Time	25		ns
$T_{OLOX}$	Low Time	30		ns
$T_{OLOH}$	Rise Time		15	ns
$T_{OHOL}$	Fall Time		15	ns

**EXTERNAL CLOCK DRIVE WAVEFORMS**

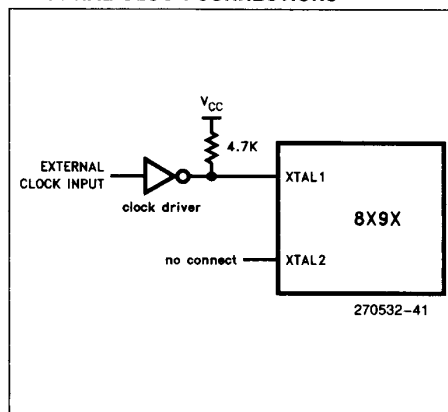


An external oscillator may encounter as much as a 100 pF load at XTAL1 when it starts up. This is due to interaction between the amplifier and its feedback capacitance. Once the external signal meets the  $V_{IL}$  and  $V_{IH}$  specifications the capacitance will not exceed 20 pF.

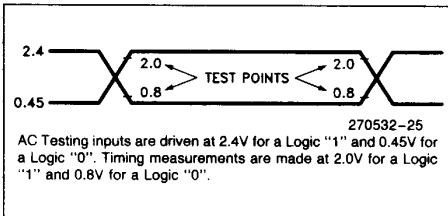
**EXTERNAL CRYSTAL CONNECTIONS**



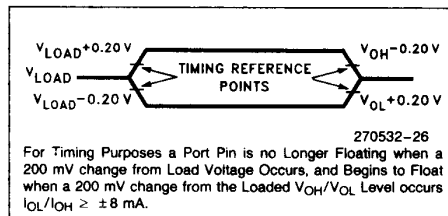
**EXTERNAL CLOCK CONNECTIONS**



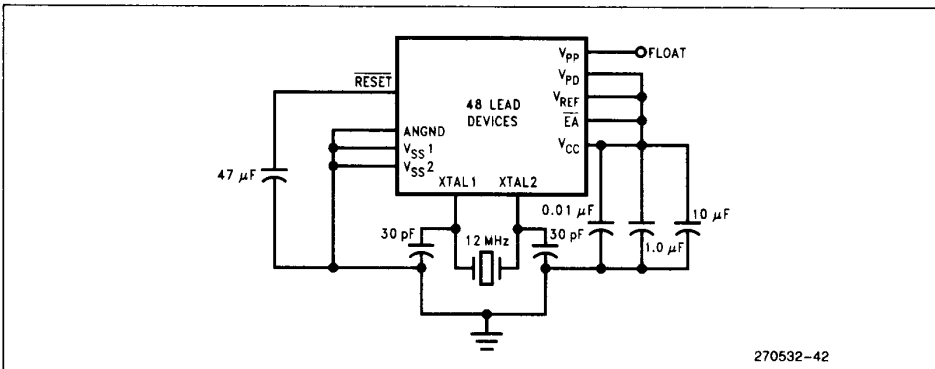
**AC TESTING INPUT, OUTPUT WAVEFORMS**



**FLOAT WAVEFORMS**



**MINIMUM HARDWARE CONFIGURATION CIRCUIT**

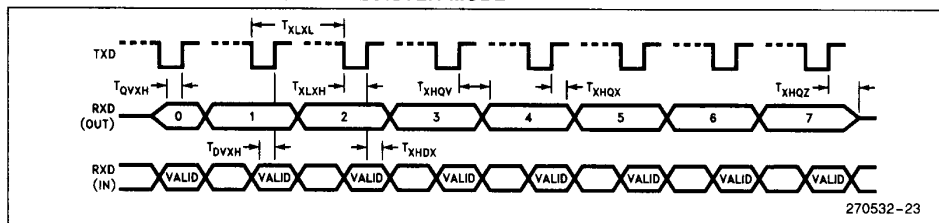


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**AC CHARACTERISTICS—SERIAL PORT—SHIFT REGISTER MODE****SERIAL PORT TIMING—SHIFT REGISTER MODE**

Test Conditions: Load Capacitance = 80 pF

Symbol	Parameter	Min	Max	Units
$T_{XLXL}$	Serial Port Clock Period	$8 T_{OSC}$		ns
$T_{XLXH}$	Serial Port Clock Falling Edge to Rising Edge	$4 T_{OSC} - 50$	$4 T_{OSC} + 50$	ns
$T_{QVXH}$	Output Data Setup to Clock Rising Edge	$3 T_{OSC}$		ns
$T_{XHQX}$	Output Data Hold After Clock Rising Edge	$2 T_{OSC} - 70$		ns
$T_{XHQV}$	Next Output Data Valid After Clock Rising Edge		$2 T_{OSC} + 50$	ns
$T_{DVXH}$	Input Data Setup to Clock Rising Edge	$2 T_{OSC} + 200$		ns
$T_{XHDX}$	Input Data Hold After Clock Rising Edge	0		ns
$T_{XHQZ}$	Last Clock Rising to Output Float		$5 T_{OSC}$	ns

**WAVEFORM—SERIAL PORT—SHIFT REGISTER MODE****SERIAL PORT WAVEFORM—SHIFT REGISTER MODE**



**A/D CONVERTER SPECIFICATIONS**

The absolute conversion accuracy is dependent on the accuracy and stability of  $V_{REF}$ .

See the MCS-96 A/D Converter Quick Reference for definition of A/D Converter Terms.

Parameter	Typical*(1)	Minimum	Maximum	Units**	Notes
Resolution		1024 10	1024 10	Levels Bits	
Absolute Error		0	±4	LSBs	
Full Scale Error	-0.5 ±0.5			LSBs	
Zero Offset Error	±0.5			LSBs	
Non-Linearity		0	±4	LSBs	
Differential Non-Linearity		> -1	+2	LSBs	
Channel-to-Channel Matching		0	±1	LSBs	
Repeatability	±0.25			LSBs	
Temperature Coefficients:					
Offset	0.009			LSB/°C	
Full Scale	0.009			LSB/°C	
Differential Non-Linearity	0.009			LSB/°C	
Off Isolation		-60		dB	1, 3
Feedthrough	-60			dB	1
$V_{CC}$ Power Supply Rejection	-60			dB	1
Input Series Resistance		1K	5K	Ω	4
DC Input Leakage		0	3.0	μA	
Sample Delay		3 $T_{OSC}$ - 50	3 $T_{OSC}$ + 50	ns	2
Sample Time		12 $T_{OSC}$ - 50	12 $T_{OSC}$ + 50	ns	
Sampling Capacitor	2			pF	

**NOTES:**

- \* These values are expected for most parts at 25°C.
- \*\* An "LSB", as used here, is defined in the MCS-96 A/D Converter Quick Reference and has a value of approximately 5 mV.
- 1. DC to 100 KHz.
- 2. For starting the A/D with an HSO Command.
- 3. Multiplexer Break-Before-Make Guaranteed.
- 4. Resistance from device pin, through internal MUX, to sample capacitor.



## EPROM SPECIFICATIONS

## EPROM PROGRAMMING OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Units
$T_A$	Ambient Temperature during Programming	20	30	°C
$V_{CC}, V_{PD}, V_{REF}^{(1)}$	Supply Voltages during Programming	4.5	5.5	V
$V_{EA}$	Programming Mode Supply Voltage	9.0	13.0	V <sup>(2)</sup>
$V_{PP}$	EPROM Programming Supply Voltage	12.50	13.0	V <sup>(2)</sup>
$V_{SS}, ANGND^{(3)}$	Digital and Analog Ground	0	0	V
$F_{OSC1}$	Oscillator Frequency during Auto and Slave Programming	6.0	6.0	MHz
$F_{OSC2}$	Oscillator Frequency during Run-Time Programming	6.0	12.0	MHz

## NOTES:

- $V_{CC}, V_{PD}$  and  $V_{REF}$  should nominally be at the same voltage during programming.
- $V_{EA}$  and  $V_{PP}$  must never exceed the maximum voltage for any amount of time or the device may be damaged.
- $V_{SS}$  and  $ANGND$  should nominally be at the same voltage (0V) during programming.

## AC EPROM PROGRAMMING CHARACTERISTICS

Symbol	Parameter	Min	Max	Units
$T_{AVLL}$	ADDRESS/COMMAND Valid to PALE Low	0		$T_{OSC}$
$T_{LLAX}$	ADDRESS/COMMAND Hold After PALE Low	80		$T_{OSC}$
$T_{DVPL}$	Output Data Setup Before $\overline{PROG}$ Low	0		$T_{OSC}$
$T_{PLDX}$	Data Hold After $\overline{PROG}$ Falling	80		$T_{OSC}$
$T_{LLLH}$	PALE Pulse Width	180		$T_{OSC}$
$T_{PLPH}$	$\overline{PROG}$ Pulse Width	$250 T_{OSC}$	$100 \mu s + 144 T_{OSC}$	
$T_{LHPL}$	PALE High to $\overline{PROG}$ Low	250		$T_{OSC}$
$T_{PHLL}$	$\overline{PROG}$ High to Next PALE Low	600		$T_{OSC}$
$T_{PHDX}$	Data Hold After $\overline{PROG}$ High	30		$T_{OSC}$
$T_{PHVV}$	$\overline{PROG}$ High to $\overline{PVER}/\overline{PD\overline{O}}$ Valid	500		$T_{OSC}$
$T_{LLVH}$	PALE Low to $\overline{PVER}/\overline{PD\overline{O}}$ High	100		$T_{OSC}$
$T_{PLDV}$	$\overline{PROG}$ Low to VERIFICATION/DUMP Data Valid	100		$T_{OSC}$
$T_{SHLL}$	RESET High to First PALE Low (not shown)	2000		$T_{OSC}$

## DC EPROM PROGRAMMING CHARACTERISTICS

Symbol	Parameter	Min	Max	Units
$I_{PP}$	$V_{PP}$ Supply Current (Whenever Programming)		100	mA







## 5. SERIAL PORT SECTION

Serial Port Flags—Reading SP\_STAT may not clear the TI or RI flag if that flag was set within two state times prior to the read. In addition, the parity error bit (RPE/RB8) may not be correct if it is read within two state times after RI is set. Use the following code to replace ORB sp\_image, SP\_STAT.

```
SP_READ: LDB TEMP, SP_STAT
         ORB SP_IMAGE, TEMP
         JBS TEMP, 5, SP_READ; if
         TI is set then read again
         JBS TEMP, 6, SP_READ; if
         RI is set then read again
         ANDB SP_IMAGE, #7FH; clear
         false RB8/RPE
         ORB SP_IMAGE, TEMP; load
         correct RB8/RPE
```

## DATA SHEET REVISION HISTORY

This data sheet (270532-008) is valid for devices with an "E" at the end of the topside tracking number. Data sheets are changed as new device information becomes available. Verify with your local Intel sales office that you have the latest version before finalizing a design or ordering devices.

The difference between -007 and -008 is the  $I_{OL}/I_{OH}$  for the float waveform testing changed from  $\pm 15$  mA to  $\pm 8$  mA.

The following differences exist between (-007) data sheet and the (-006).

1. The Express (extended temperature and burn-in options) were added to this data sheet. The 8X98 Express data sheet (270914-002) is now obsolete.
2. Changes were made to the format of the data sheet and the SFR descriptions were removed. No specification changes were made.
3. Added Reserved Location 201CH errata.

The following differences exist between the -006 data sheet and the -005 data sheet.

1. The -005 data sheet was valid for devices marked with a "D" at the end of the top side tracking number.
2. The following errata were removed: RESET and the Quasi-Bidirectional Ports, Software RESET Timing, and Using T2CLK as the source for Timer2.
3. The HSI FIFO Operation errata definition was changed to match a change in the HSI FIFO operation.

The following differences exist between the -005 data sheet and the -004 data sheet.

1. Most of the functional description has been removed. This information is in the MCS-96 Architectural Overview.
2. Information on programming the Chip Configuration Register has been added.
3.  $T_{XHGX}$  changed from Min =  $2 T_{OSC} - 50$  ns to Min =  $2 T_{OSC} - 70$  ns.
4.  $T_{OLOX}$  changed from Min = 25 ns to Min = 30 ns.
5. Added AC timings specifications to clarify Write Strobe Mode specifications.
6. The differences between the 8X9XBH and the 8X98 have been added.
7. An errata has been added changing the recommendation for address 2019H from 0FFH to 20H.

Differences between the -004 and -003 data sheets.

1. All EPROM programming mode information has been moved to the Hardware Design Information Chapter.
2. CCB RESET FETCH and JBS/JBC on Port 0 anomalies have been corrected on the current stepings of the 8X98.
3. New information regarding T2CLK and new information about RESET of the Quasi Ports have been added to the Errata section.
4. The Extended Reset errata has been eliminated on the silicon and in the data sheet.
5. HSI Mode register is undefined until the user code initializes this register.
6. Minimum DNL us now  $> -1$  LSB.
7. HSI FIFO overflow description added.

Differences between the -002 and -003 data sheets.

1. All 8798 EPROM information has been added as a complete section after the Analog Section.
2. The chip configuration byte values now indicate the use of WRITE STROBE with 8-bit systems. Write Strobe design text was added to the explanation.
3. The interrupt information now includes a worst case timing diagram.
4. The EPROM 8798 was added as necessary throughout the text.
5. NMI pin information was deleted.
6. Reset Register Status was added and the state of the HSO pins after RESET.
7. A diagram of the Interrupt Pending Register is now included.



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8. A diagram of the PSW Register was added.
9.  $V_{IL1}$  was deleted. This was a RESET pin characteristic that has been improved to match the other characteristics.
10. The Differential Non-Linearity specification in the A/D converter specifications was corrected to read +2 LSBs.
11. Power On Reset — New information on Extended Reset Time was added to the Errata Section.

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